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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	20MHz
Connectivity	-
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	5
Program Memory Size	1.75KB (1K x 14)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	64 x 8
Voltage - Supply (Vcc/Vdd)	2V ~ 5.5V
Data Converters	-
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	8-SOIC (0.154", 3.90mm Width)
Supplier Device Package	8-SOIC
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic12f609-i-sn

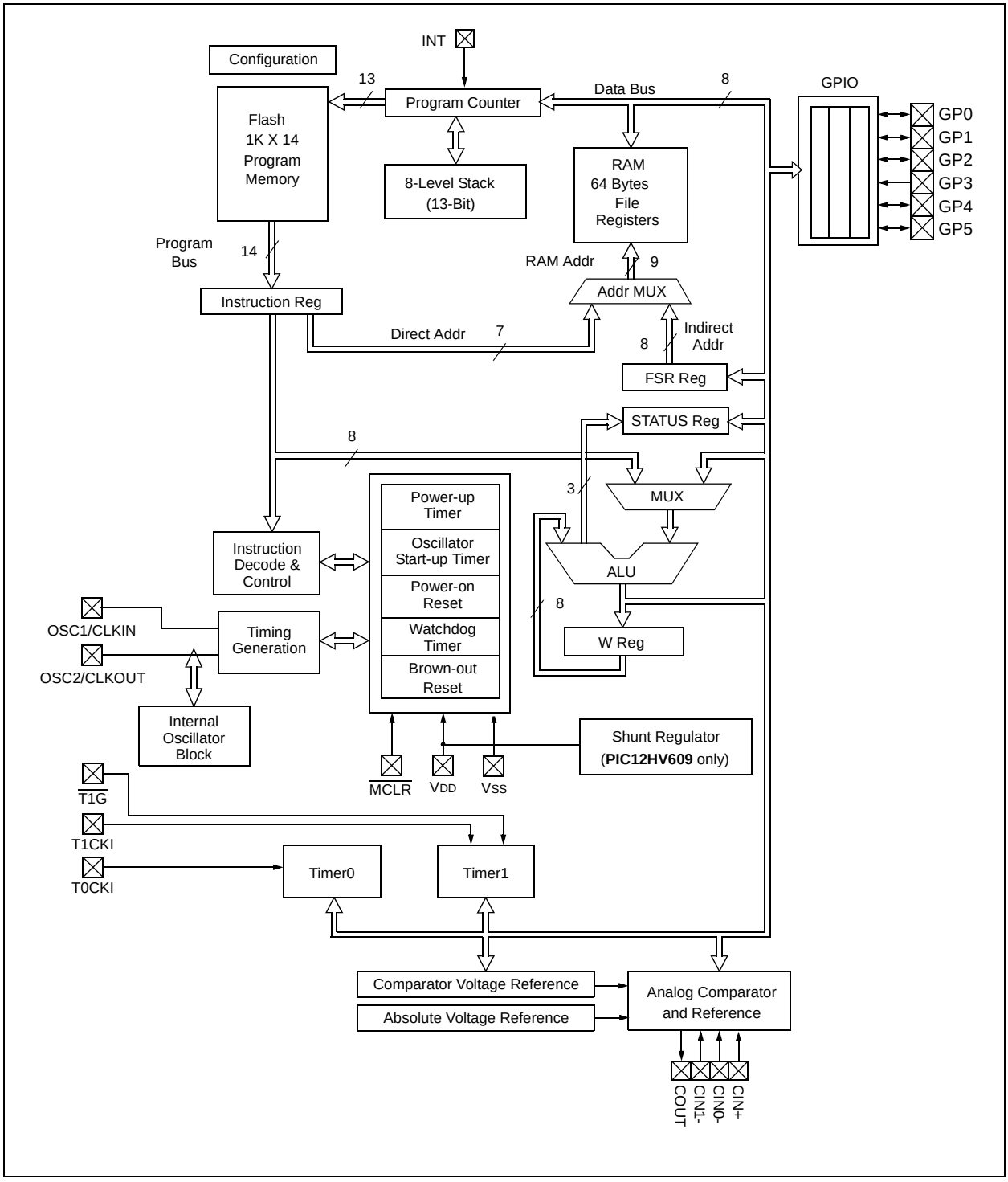
1.0 DEVICE OVERVIEW

The PIC12F609/615/617/12HV609/615 devices are covered by this data sheet. They are available in 8-pin PDIP, SOIC, MSOP and DFN packages.

Block Diagrams and pinout descriptions of the devices are as follows:

- PIC12F609/HV609 (Figure 1-1, Table 1-1)
- PIC12F615/617/HV615 (Figure 1-2, Table 1-2)

FIGURE 1-1: PIC12F609/HV609 BLOCK DIAGRAM



2.2.2.2 OPTION Register

The OPTION register is a readable and writable register, which contains various control bits to configure:

- Timer0/WDT prescaler
- External GP2/INT interrupt
- Timer0
- Weak pull-ups on GPIO

Note: To achieve a 1:1 prescaler assignment for Timer0, assign the prescaler to the WDT by setting PSA bit to '1' of the OPTION register. See **Section 6.1.3 "Software Programmable Prescaler"**.

REGISTER 2-2: OPTION_REG: OPTION REGISTER

R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1
$\overline{GPPU}$	INTEDG	T0CS	T0SE	PSA	PS2	PS1	PS0
bit 7							bit 0

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'	
-n = Value at POR	'1' = Bit is set	'0' = Bit is cleared	x = Bit is unknown

bit 7 **$\overline{GPPU}$:** GPIO Pull-up Enable bit
1 = GPIO pull-ups are disabled
0 = GPIO pull-ups are enabled by individual PORT latch values

bit 6 **INTEDG:** Interrupt Edge Select bit
1 = Interrupt on rising edge of GP2/INT pin
0 = Interrupt on falling edge of GP2/INT pin

bit 5 **T0CS:** Timer0 Clock Source Select bit
1 = Transition on GP2/T0CKI pin
0 = Internal instruction cycle clock (FOSC/4)

bit 4 **T0SE:** Timer0 Source Edge Select bit
1 = Increment on high-to-low transition on GP2/T0CKI pin
0 = Increment on low-to-high transition on GP2/T0CKI pin

bit 3 **PSA:** Prescaler Assignment bit
1 = Prescaler is assigned to the WDT
0 = Prescaler is assigned to the Timer0 module

bit 2-0 **PS<2:0>:** Prescaler Rate Select bits

BIT VALUE	TIMER0 RATE	WDT RATE
000	1 : 2	1 : 1
001	1 : 4	1 : 2
010	1 : 8	1 : 4
011	1 : 16	1 : 8
100	1 : 32	1 : 16
101	1 : 64	1 : 32
110	1 : 128	1 : 64
111	1 : 256	1 : 128

3.0 FLASH PROGRAM MEMORY SELF READ/SELF WRITE CONTROL (FOR PIC12F617 ONLY)

The Flash program memory is readable and writable during normal operation (full V_{DD} range). This memory is not directly mapped in the register file space. Instead, it is indirectly addressed through the Special Function Registers (see Registers 3-1 to 3-5). There are six SFRs used to read and write this memory:

- PMCON1
- PMCON2
- PMDATL
- PMDATH
- PMADRL
- PMADRH

When interfacing the program memory block, the PMDATL and PMDATH registers form a two-byte word which holds the 14-bit data for read/write, and the PMADRL and PMADRH registers form a two-byte word which holds the 13-bit address of the Flash location being accessed. These devices have 2K words of program Flash with an address range from 0000h to 07FFh.

The program memory allows single word read and a by four word write. A four word write automatically erases the row of the location and writes the new data (erase before write).

The write time is controlled by an on-chip timer. The write/erase voltages are generated by an on-chip charge pump rated to operate over the voltage range of the device for byte or word operations.

When the device is code-protected, the CPU may continue to read and write the Flash program memory.

Depending on the settings of the Flash Program Memory Enable (WRT<1:0>) bits, the device may or may not be able to write certain blocks of the program memory, however, reads of the program memory are allowed.

When the Flash program memory Code Protection ($\overline{CP}$) bit in the Configuration Word register is enabled, the program memory is code-protected, and the device programmer (ICSP™) cannot access data or program memory.

3.1 PMADRH and PMADRL Registers

The PMADRH and PMADRL registers can address up to a maximum of 8K words of program memory.

When selecting a program address value, the Most Significant Byte (MSB) of the address is written to the PMADRH register and the Least Significant Byte (LSB) is written to the PMADRL register.

3.2 PMCON1 and PMCON2 Registers

PMCON1 is the control register for the data program memory accesses.

Control bits RD and WR initiate read and write, respectively. These bits cannot be cleared, only set in software. They are cleared in hardware at completion of the read or write operation. The inability to clear the WR bit in software prevents the accidental premature termination of a write operation.

The WREN bit, when set, will allow a write operation. On power-up, the WREN bit is clear.

PMCON2 is not a physical register. Reading PMCON2 will read all '0's. The PMCON2 register is used exclusively in the Flash memory write sequence.

FIGURE 3-2: BLOCK WRITES TO 2K FLASH PROGRAM MEMORY

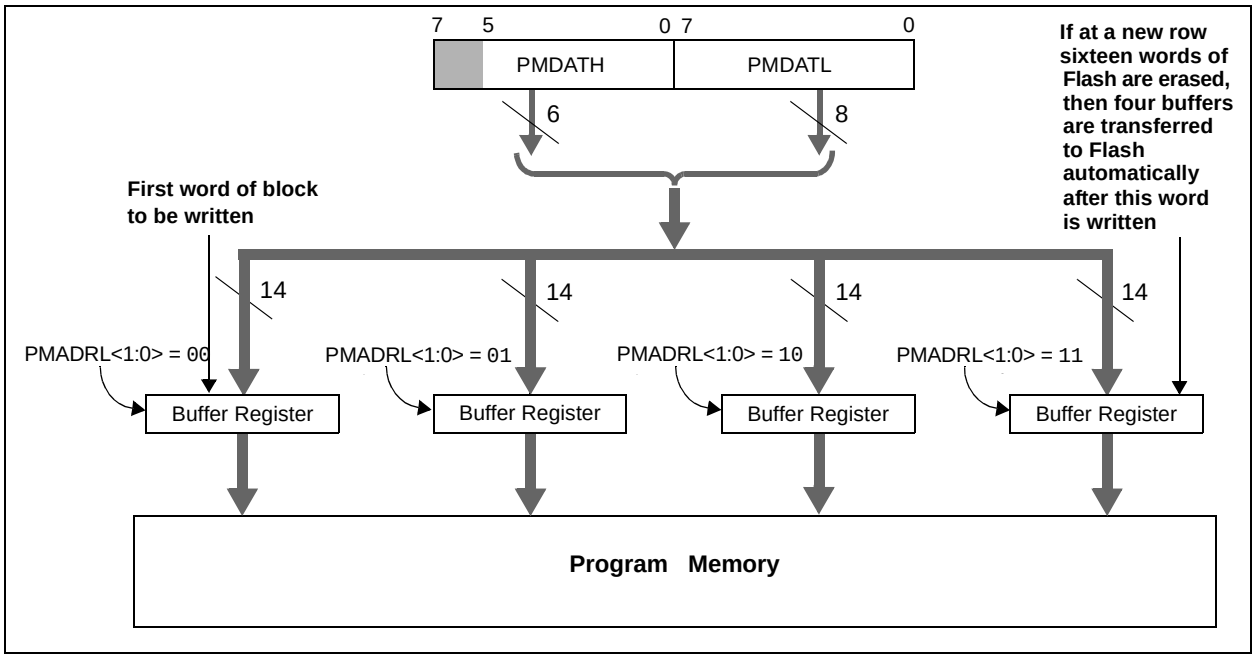
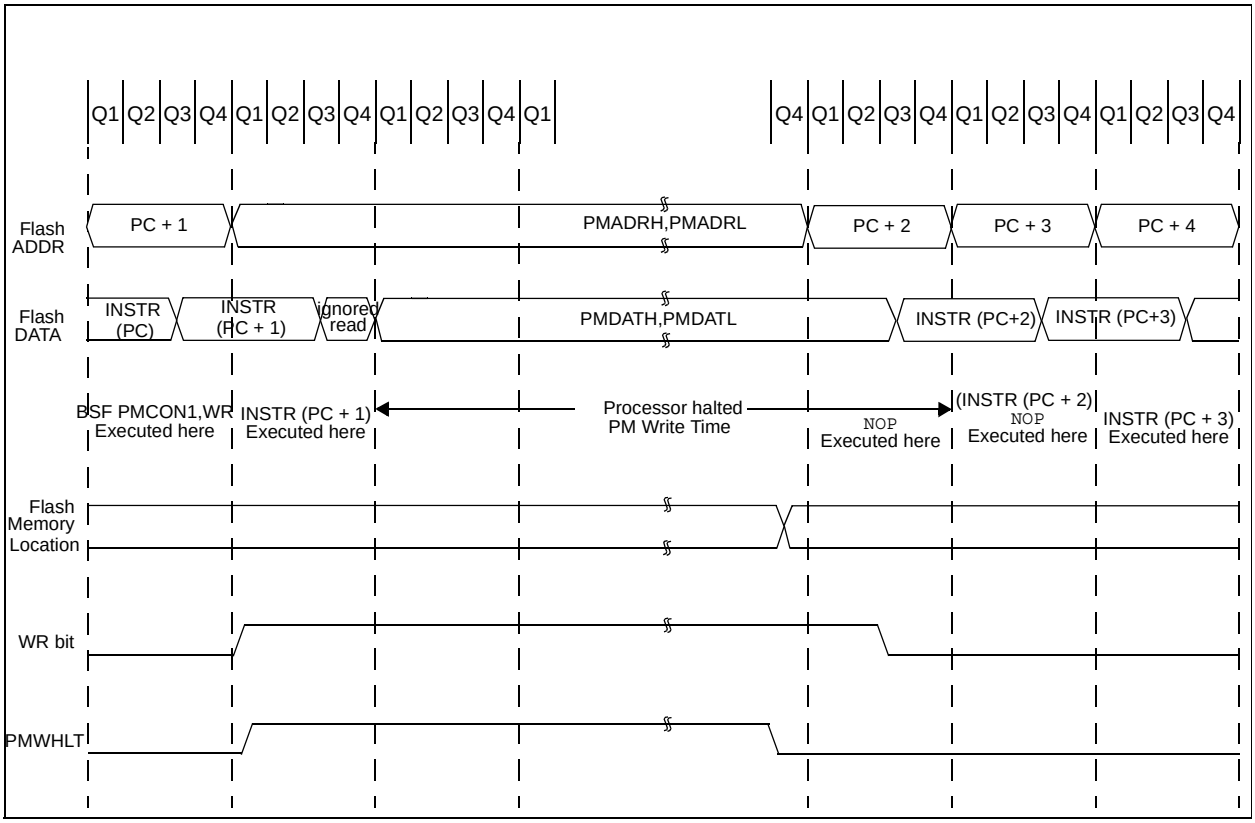


FIGURE 3-3: FLASH PROGRAM MEMORY LONG WRITE CYCLE EXECUTION

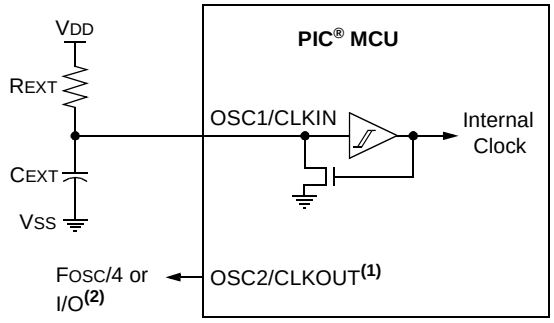


4.3.4 EXTERNAL RC MODES

The external Resistor-Capacitor (RC) modes support the use of an external RC circuit. This allows the designer maximum flexibility in frequency choice while keeping costs to a minimum when clock accuracy is not required. There are two modes: RC and RCIO.

In RC mode, the RC circuit connects to OSC1. OSC2/CLKOUT outputs the RC oscillator frequency divided by 4. This signal may be used to provide a clock for external circuitry, synchronization, calibration, test or other application requirements. Figure 4-5 shows the external RC mode connections.

FIGURE 4-5: EXTERNAL RC MODES



Recommended values: 10 kΩ ≤ REXT ≤ 100 kΩ, <3V
3 kΩ ≤ REXT ≤ 100 kΩ, 3-5V
CEXT > 20 pF, 2-5V

Note 1: Alternate pin functions are listed in **Section 1.0 "Device Overview"**.

2: Output depends upon RC or RCIO Clock mode.

In RCIO mode, the RC circuit is connected to OSC1. OSC2 becomes an additional general purpose I/O pin.

The RC oscillator frequency is a function of the supply voltage, the resistor (REXT) and capacitor (CEXT) values and the operating temperature. Other factors affecting the oscillator frequency are:

- threshold voltage variation
- component tolerances
- packaging variations in capacitance

The user also needs to take into account variation due to tolerance of external RC components used.

4.4 Internal Clock Modes

The Oscillator module provides a selectable system clock source of either 4 MHz or 8 MHz. The selectable frequency is configured through the IOSCFS bit of the Configuration Word.

The frequency of the internal oscillator can be trimmed with a calibration value in the OSCTUNE register.

4.4.1 INTOSC AND INTOSCIO MODES

The INTOSC and INTOSCIO modes configure the internal oscillators as the system clock source when the device is programmed using the oscillator selection or the FOSC<2:0> bits in the Configuration Word register (CONFIG). See **Section 12.0 "Special Features of the CPU"** for more information.

In **INTOSC** mode, OSC1/CLKIN is available for general purpose I/O. OSC2/CLKOUT outputs the selected internal oscillator frequency divided by 4. The CLKOUT signal may be used to provide a clock for external circuitry, synchronization, calibration, test or other application requirements.

In **INTOSCIO** mode, OSC1/CLKIN and OSC2/CLKOUT are available for general purpose I/O.

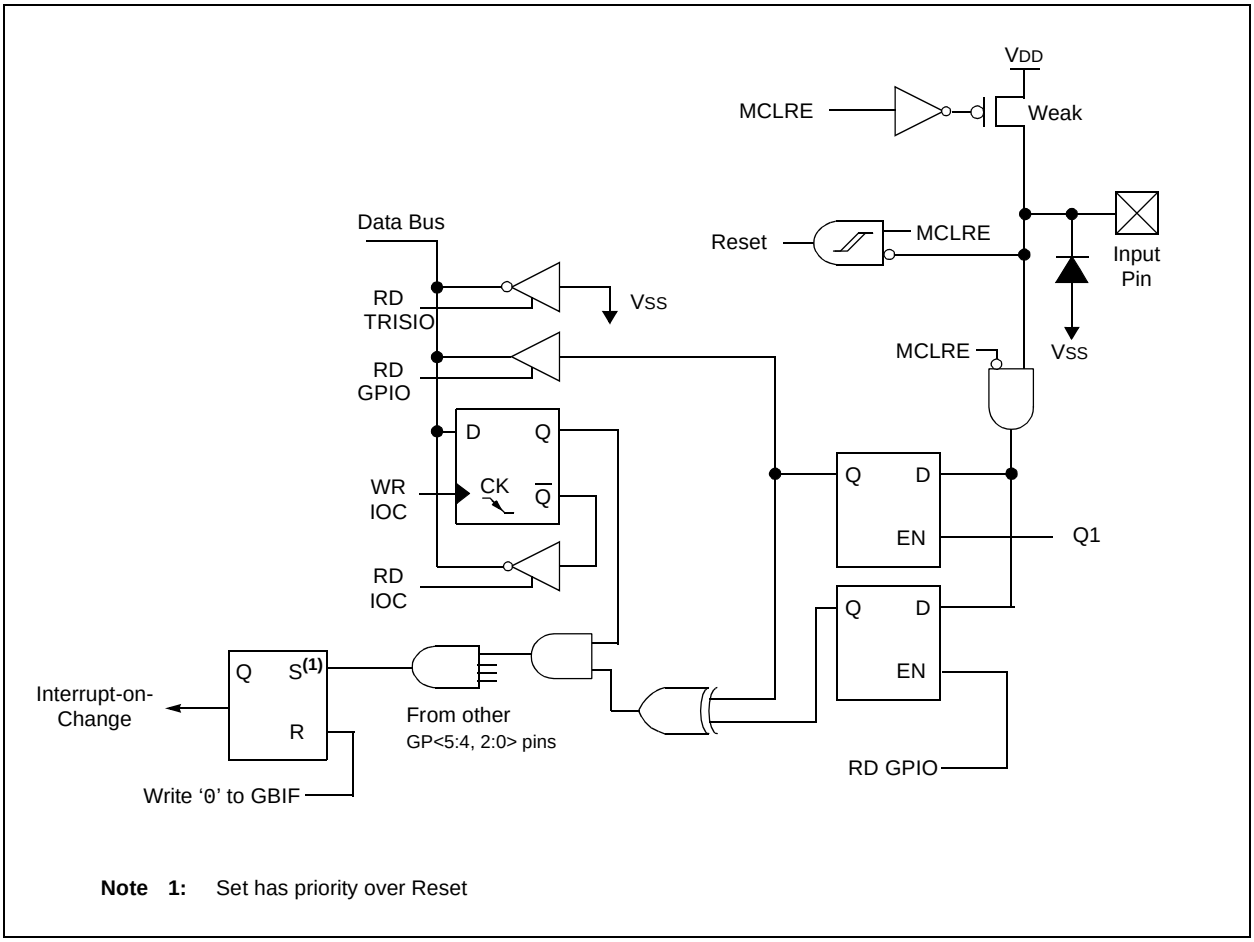
5.2.4.4 GP3/$\overline{T1G}$[1, 2]/$\overline{MCLR}$/V_{PP}

Figure 5-3 shows the diagram for this pin. The GP3 pin is configurable to function as one of the following:

- a general purpose input
- a Timer1 gate (count enable), alternate pin[1, 2]
- as Master Clear Reset with weak pull-up

Note 1:	Alternate pin function.
2:	PIC12F615/617/HV615 only.

FIGURE 5-3: BLOCK DIAGRAM OF GP3



Note 1: Set has priority over Reset

TABLE 10-1: ADC CLOCK PERIOD (T_{AD}) VS. DEVICE OPERATING FREQUENCIES (VDD ≥ 3.0V)

ADC Clock Period (T_{AD})		Device Frequency (F_{OSC})			
ADC Clock Source	**ADCS<2:0>**	**20 MHz**	**8 MHz**	**4 MHz**	**1 MHz**
F_{OSC}/2	000	100 ns(2)	250 ns(2)	500 ns(2)	2.0 μs
F_{OSC}/4	100	200 ns(2)	500 ns(2)	1.0 μs(2)	4.0 μs
F_{OSC}/8	001	400 ns(2)	1.0 μs(2)	2.0 μs	8.0 μs(3)
F_{OSC}/16	101	800 ns(2)	2.0 μs	4.0 μs	16.0 μs(3)
F_{OSC}/32	010	1.6 μs	4.0 μs	8.0 μs(3)	32.0 μs(3)
F_{OSC}/64	110	3.2 μs	8.0 μs(3)	16.0 μs(3)	64.0 μs(3)
F_{RC}	x11	2-6 μs(1,4)	2-6 μs(1,4)	2-6 μs(1,4)	2-6 μs(1,4)

Legend: Shaded cells are outside of recommended range.

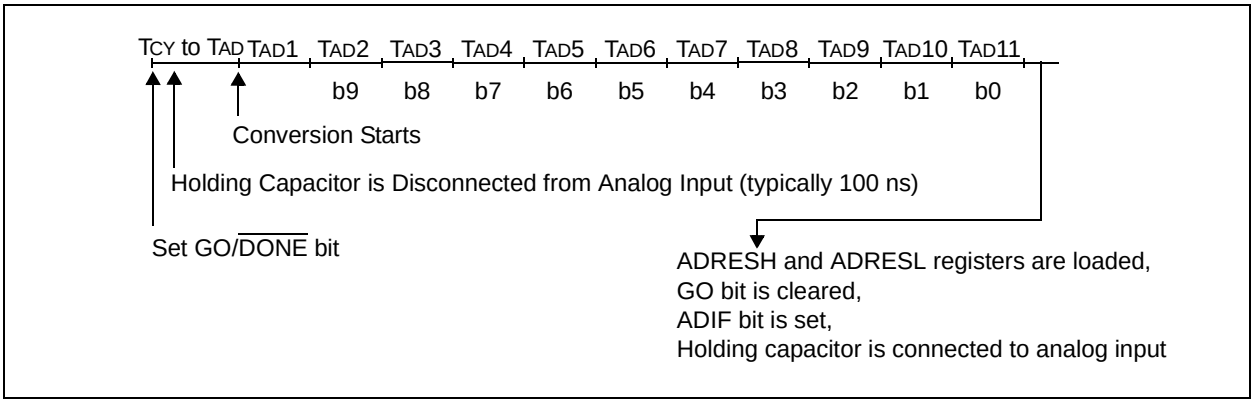
Note 1: The F_{RC} source has a typical T_{AD} time of 4 μs for V_{DD} > 3.0V.

2: These values violate the minimum required T_{AD} time.

3: For faster conversion times, the selection of another clock source is recommended.

4: When the device frequency is greater than 1 MHz, the F_{RC} clock source is only recommended if the conversion will be performed during Sleep.

FIGURE 10-2: ANALOG-TO-DIGITAL CONVERSION T_{AD} CYCLES



10.1.5 INTERRUPTS

The ADC module allows for the ability to generate an interrupt upon completion of an Analog-to-Digital conversion. The ADC interrupt flag is the ADIF bit in the PIR1 register. The ADC interrupt enable is the ADIE bit in the PIE1 register. The ADIF bit must be cleared in software.

Note:	The ADIF bit is set at the completion of every conversion, regardless of whether or not the ADC interrupt is enabled.

This interrupt can be generated while the device is operating or while in Sleep. If the device is in Sleep, the interrupt will wake-up the device. Upon waking from Sleep, the next instruction following the SLEEP instruction is always executed. If the user is attempting to wake-up from Sleep and resume in-line code execution, the global interrupt must be disabled. If the global interrupt is enabled, execution will switch to the Interrupt Service Routine.

Please see **Section 10.1.5 "Interrupts"** for more information.

11.4.2 START-UP CONSIDERATIONS

When any PWM mode is used, the application hardware must use the proper external pull-up and/or pull-down resistors on the PWM output pins.

Note:	When the microcontroller is released from Reset, all of the I/O pins are in the high-impedance state. The external circuits must keep the power switch devices in the OFF state until the microcontroller drives the I/O pins with the proper signal levels or activates the PWM output(s).

The CCP1M<1:0> bits of the CCP1CON register allow the user to choose whether the PWM output signals are active-high or active-low for each PWM output pin (P1A and P1B). The PWM output polarities must be selected before the PWM pin output drivers are enabled. Changing the polarity configuration while the PWM pin output drivers are enable is not recommended since it may result in damage to the application circuits.

The P1A and P1B output latches may not be in the proper states when the PWM module is initialized. Enabling the PWM pin output drivers at the same time as the Enhanced PWM modes may cause damage to the application circuit. The Enhanced PWM modes must be enabled in the proper Output mode and complete a full PWM cycle before configuring the PWM pin output drivers. The completion of a full PWM cycle is indicated by the TMR2IF bit of the PIR1 register being set as the second PWM period begins.

11.4.3 OPERATION DURING SLEEP

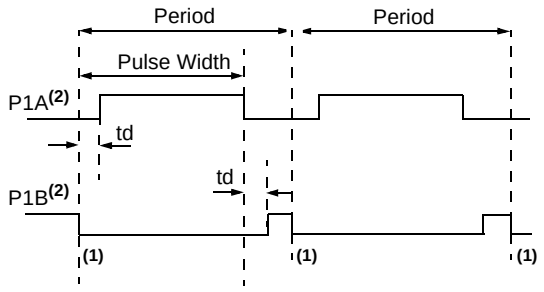
When the device is placed in sleep, the allocated timer will not increment and the state of the module will not change. If the CCP1 pin is driving a value, it will continue to drive that value. When the device wakes up, it will continue from this state.

11.4.6 PROGRAMMABLE DEAD-BAND DELAY MODE

In Half-Bridge applications where all power switches are modulated at the PWM frequency, the power switches normally require more time to turn off than to turn on. If both the upper and lower power switches are switched at the same time (one turned on, and the other turned off), both switches may be on for a short period of time until one switch completely turns off. During this brief interval, a very high current (*shoot-through current*) will flow through both power switches, shorting the bridge supply. To avoid this potentially destructive shoot-through current from flowing during switching, turning on either of the power switches is normally delayed to allow the other switch to completely turn off.

In Half-Bridge mode, a digitally programmable dead-band delay is available to avoid shoot-through current from destroying the bridge power switches. The delay occurs at the signal transition from the non-active state to the active state. See Figure 11-13 for illustration. The lower seven bits of the associated PWMxCON register (Register 11-3) sets the delay period in terms of microcontroller instruction cycles (TCY or 4 TOSC).

FIGURE 11-13: EXAMPLE OF HALF-BRIDGE PWM OUTPUT

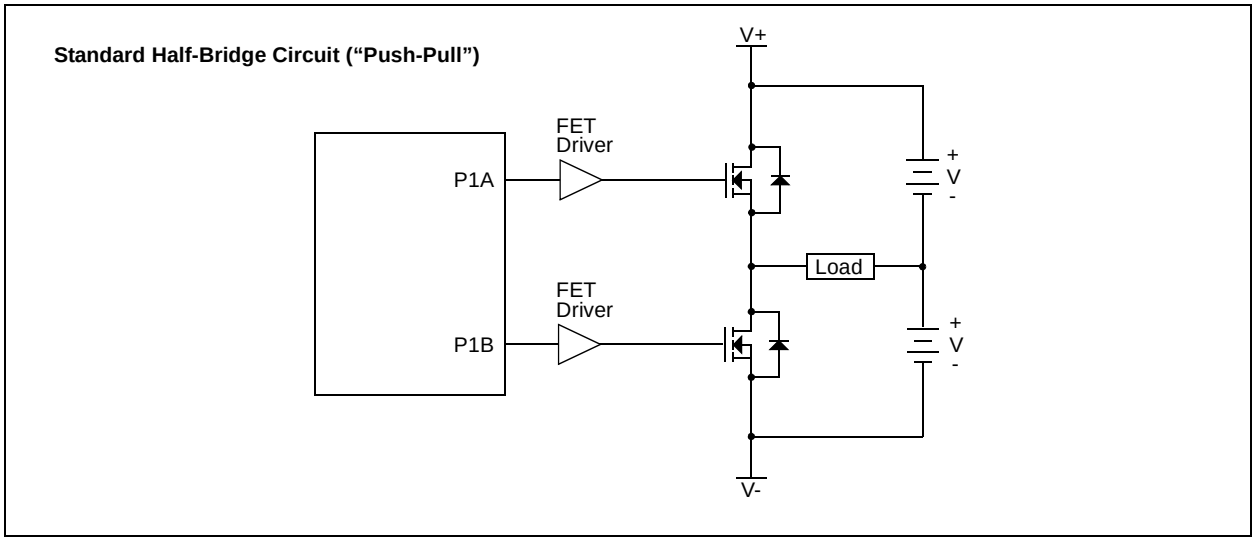


td = Dead-Band Delay

Note 1: At this time, the TMR2 register is equal to the PR2 register.

2: Output signals are shown as active-high.

FIGURE 11-14: EXAMPLE OF HALF-BRIDGE APPLICATIONS



NOTES:

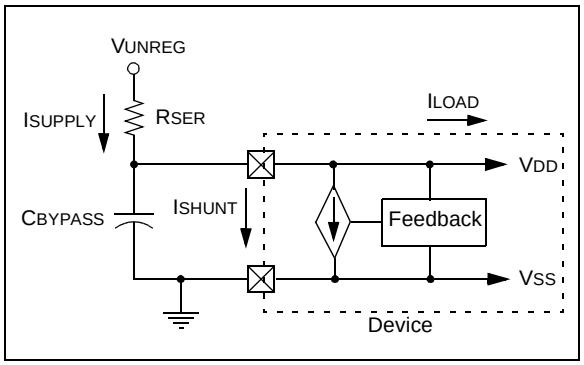
13.0 VOLTAGE REGULATOR

The PIC12HV609/HV615 devices include a permanent internal 5 volt (nominal) shunt regulator in parallel with the VDD pin. This eliminates the need for an external voltage regulator in systems sourced by an unregulated supply. All external devices connected directly to the VDD pin will share the regulated supply voltage and contribute to the total VDD supply current (ILOAD).

13.1 Regulator Operation

A shunt regulator generates a specific supply voltage by creating a voltage drop across a pass resistor RSER. The voltage at the VDD pin of the microcontroller is monitored and compared to an internal voltage reference. The current through the resistor is then adjusted, based on the result of the comparison, to produce a voltage drop equal to the difference between the supply voltage VUNREG and the VDD of the microcontroller. See Figure 13-1 for voltage regulator schematic.

FIGURE 13-1: VOLTAGE REGULATOR



An external current limiting resistor, RSER, located between the unregulated supply, VUNREG, and the VDD pin, drops the difference in voltage between VUNREG and VDD. RSER must be between RMAX and RMIN as defined by Equation 13-1.

EQUATION 13-1: RSER LIMITING RESISTOR

$$R_{MAX} = \frac{(VU_{MIN} - 5V)}{1.05 \bullet (4\ mA + I_{LOAD})}$$

$$R_{MIN} = \frac{(VU_{MAX} - 5V)}{0.95 \bullet (50\ mA)}$$

Where:

RMAX = maximum value of RSER (ohms)

RMIN = minimum value of RSER (ohms)

VUMIN = minimum value of VUNREG

VUMAX = maximum value of VUNREG

VDD = regulated voltage (5V nominal)

ILOAD = maximum expected load current in mA including I/O pin currents and external circuits connected to VDD.

1.05 = compensation for +5% tolerance of RSER

0.95 = compensation for -5% tolerance of RSER

13.2 Regulator Considerations

The supply voltage VUNREG and load current are not constant. Therefore, the current range of the regulator is limited. Selecting a value for RSER must take these three factors into consideration.

Since the regulator uses the band gap voltage as the regulated voltage reference, this voltage reference is permanently enabled in the PIC12HV609/HV615 devices.

The shunt regulator will still consume current when below operating voltage range for the shunt regulator.

13.3 Design Considerations

For more information on using the shunt regulator and managing current load, see Application Note AN1035, "*Designing with HV Microcontrollers"* (DS01035).

14.2 Instruction Descriptions

ADDLW	Add literal and W
Syntax:	[*label*] ADDLW k
Operands:	0 ≤ k ≤ 255
Operation:	(W) + k → (W)
Status Affected:	C, DC, Z
Description:	The contents of the W register are added to the eight-bit literal 'k' and the result is placed in the W register.

ADDWF	Add W and f
Syntax:	[*label*] ADDWF f,d
Operands:	0 ≤ f ≤ 127 d ∈ [0,1]
Operation:	(W) + (f) → (destination)
Status Affected:	C, DC, Z
Description:	Add the contents of the W register with register 'f'. If 'd' is '0', the result is stored in the W register. If 'd' is '1', the result is stored back in register 'f'.

ANDLW	AND literal with W
Syntax:	[*label*] ANDLW k
Operands:	0 ≤ k ≤ 255
Operation:	(W) .AND. (k) → (W)
Status Affected:	Z
Description:	The contents of W register are AND'ed with the eight-bit literal 'k'. The result is placed in the W register.

ANDWF	AND W with f
Syntax:	[*label*] ANDWF f,d
Operands:	0 ≤ f ≤ 127 d ∈ [0,1]
Operation:	(W) .AND. (f) → (destination)
Status Affected:	Z
Description:	AND the W register with register 'f'. If 'd' is '0', the result is stored in the W register. If 'd' is '1', the result is stored back in register 'f'.

BCF	Bit Clear f
Syntax:	[*label*] BCF f,b
Operands:	0 ≤ f ≤ 127 0 ≤ b ≤ 7
Operation:	0 → (f<b>)
Status Affected:	None
Description:	Bit 'b' in register 'f' is cleared.

BSF	Bit Set f
Syntax:	[*label*] BSF f,b
Operands:	0 ≤ f ≤ 127 0 ≤ b ≤ 7
Operation:	1 → (f<b>)
Status Affected:	None
Description:	Bit 'b' in register 'f' is set.

BTFSC	Bit Test f, Skip if Clear
Syntax:	[*label*] BTFSC f,b
Operands:	0 ≤ f ≤ 127 0 ≤ b ≤ 7
Operation:	skip if (f<b>) = 0
Status Affected:	None
Description:	If bit 'b' in register 'f' is '1', the next instruction is executed. If bit 'b' in register 'f' is '0', the next instruction is discarded, and a NOP is executed instead, making this a two-cycle instruction.

MOVF **Move f**

Syntax: [*label*] MOVF f,d

Operands: $0 \le f \le 127$
$d \in [0,1]$

Operation: (f) → (dest)

Status Affected: Z

Description: The contents of register 'f' is moved to a destination dependent upon the status of 'd'. If d = 0, destination is W register. If d = 1, the destination is file register 'f' itself. d = 1 is useful to test a file register since Status flag Z is affected.

Words: 1

Cycles: 1

Example:
```
MOVF    FSR, 0
```
After Instruction
W = value in FSR register
Z = 1

MOVWF **Move W to f**

Syntax: [*label*] MOVWF f

Operands: $0 \le f \le 127$

Operation: (W) → (f)

Status Affected: None

Description: Move data from W register to register 'f'.

Words: 1

Cycles: 1

Example:
```
MOVW    OPTION
F
```
Before Instruction
OPTION = 0xFF
W = 0x4F
After Instruction
OPTION = 0x4F
W = 0x4F

MOVLW **Move literal to W**

Syntax: [*label*] MOVLW k

Operands: $0 \le k \le 255$

Operation: k → (W)

Status Affected: None

Description: The eight-bit literal 'k' is loaded into W register. The "don't cares" will assemble as '0's.

Words: 1

Cycles: 1

Example:
```
MOVLW   0x5A
```
After Instruction
W = 0x5A

NOP **No Operation**

Syntax: [*label*] NOP

Operands: None

Operation: No operation

Status Affected: None

Description: No operation.

Words: 1

Cycles: 1

Example:
```
NOP
```

15.2 MPLAB C Compilers for Various Device Families

The MPLAB C Compiler code development systems are complete ANSI C compilers for Microchip's PIC18, PIC24 and PIC32 families of microcontrollers and the dsPIC30 and dsPIC33 families of digital signal controllers. These compilers provide powerful integration capabilities, superior code optimization and ease of use.

For easy source level debugging, the compilers provide symbol information that is optimized to the MPLAB IDE debugger.

15.3 HI-TECH C for Various Device Families

The HI-TECH C Compiler code development systems are complete ANSI C compilers for Microchip's PIC family of microcontrollers and the dsPIC family of digital signal controllers. These compilers provide powerful integration capabilities, omniscient code generation and ease of use.

For easy source level debugging, the compilers provide symbol information that is optimized to the MPLAB IDE debugger.

The compilers include a macro assembler, linker, preprocessor, and one-step driver, and can run on multiple platforms.

15.4 MPASM Assembler

The MPASM Assembler is a full-featured, universal macro assembler for PIC10/12/16/18 MCUs.

The MPASM Assembler generates relocatable object files for the MPLINK Object Linker, Intel® standard HEX files, MAP files to detail memory usage and symbol reference, absolute LST files that contain source lines and generated machine code and COFF files for debugging.

The MPASM Assembler features include:

- Integration into MPLAB IDE projects
- User-defined macros to streamline assembly code
- Conditional assembly for multi-purpose source files
- Directives that allow complete control over the assembly process

15.5 MPLINK Object Linker/ MPLIB Object Librarian

The MPLINK Object Linker combines relocatable objects created by the MPASM Assembler and the MPLAB C18 C Compiler. It can link relocatable objects from precompiled libraries, using directives from a linker script.

The MPLIB Object Librarian manages the creation and modification of library files of precompiled code. When a routine from a library is called from a source file, only the modules that contain that routine will be linked in with the application. This allows large libraries to be used efficiently in many different applications.

The object linker/library features include:

- Efficient linking of single libraries instead of many smaller files
- Enhanced code maintainability by grouping related modules together
- Flexible creation of libraries with easy module listing, replacement, deletion and extraction

15.6 MPLAB Assembler, Linker and Librarian for Various Device Families

MPLAB Assembler produces relocatable machine code from symbolic assembly language for PIC24, PIC32 and dsPIC devices. MPLAB C Compiler uses the assembler to produce its object file. The assembler generates relocatable object files that can then be archived or linked with other relocatable object files and archives to create an executable file. Notable features of the assembler include:

- Support for the entire device instruction set
- Support for fixed-point and floating-point data
- Command line interface
- Rich directive set
- Flexible macro language
- MPLAB IDE compatibility

16.4 DC Characteristics: PIC12F609/615/617 - I (Industrial)

DC CHARACTERISTICS		Standard Operating Conditions (unless otherwise stated) Operating temperature -40°C ≤ TA ≤ +85°C for industrial					
Param No.	Device Characteristics	Min	Typ†	Max	Units	Conditions	
						VDD	Note
D020	**Power-down Base Current (IPD)(2)**	—	0.05	0.9	µA	2.0	WDT, BOR, Comparator, VREF and T1OSC disabled
		—	0.15	1.2	µA	3.0	
	PIC12F609/615/617	—	0.35	1.5	µA	5.0	
			150	500	nA	3.0	-40°C ≤ TA ≤ +25°C for industrial
D021		—	0.5	1.5	µA	2.0	WDT Current(1)
		—	2.5	4.0	µA	3.0	
		—	9.5	17	µA	5.0	
D022		—	5.0	9	µA	3.0	BOR Current(1)
		—	6.0	12	µA	5.0	
D023		—	50	60	µA	2.0	Comparator Current(1), single comparator enabled
		—	55	65	µA	3.0	
		—	60	75	µA	5.0	
D024		—	30	40	µA	2.0	CVREF Current(1) (high range)
		—	45	60	µA	3.0	
		—	75	105	µA	5.0	
D025*		—	39	50	µA	2.0	CVREF Current(1) (low range)
		—	59	80	µA	3.0	
		—	98	130	µA	5.0	
D026		—	5.5	10	µA	2.0	T1OSC Current(1), 32.768 kHz
		—	7.0	12	µA	3.0	
		—	8.5	14	µA	5.0	
D027		—	0.2	1.6	µA	3.0	A/D Current(1), no conversion in progress
		—	0.36	1.9	µA	5.0	

* These parameters are characterized but not tested.

† Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: The peripheral current is the sum of the base IDD or IPD and the additional current consumed when this peripheral is enabled. The peripheral Δ current can be determined by subtracting the base IDD or IPD current from this limit. Max values should be used when calculating total current consumption.

2: The power-down current in Sleep mode does not depend on the oscillator type. Power-down current is measured with the part in Sleep mode, with all I/O pins in high-impedance state and tied to VDD.

16.9 Thermal Considerations

Standard Operating Conditions (unless otherwise stated) Operating temperature -40°C ≤ TA ≤ +125°C					
Param No.	**Sym**	**Characteristic**	**Typ**	**Units**	**Conditions**
TH01	θJA	Thermal Resistance Junction to Ambient	84.6*	C/W	8-pin PDIP package
			149.5*	C/W	8-pin SOIC package
			211*	C/W	8-pin MSOP package
			60*	C/W	8-pin DFN 3x3mm package
			44*	C/W	8-pin DFN 4x4mm package
TH02	θJC	Thermal Resistance Junction to Case	41.2*	C/W	8-pin PDIP package
			39.9*	C/W	8-pin SOIC package
			39*	C/W	8-pin MSOP package
			9*	C/W	8-pin DFN 3x3mm package
			3.0*	C/W	8-pin DFN 4x4mm package
TH03	TDIE	Die Temperature	150*	C	
TH04	PD	Power Dissipation	—	W	PD = PINTERNAL + PI/O
TH05	PINTERNAL	Internal Power Dissipation	—	W	PINTERNAL = IDD x VDD **(NOTE 1)**
TH06	PI/O	I/O Power Dissipation	—	W	PI/O = Σ (IOL * VOL) + Σ (IOH * (VDD - VOH))
TH07	PDER	Derated Power	—	W	PDER = PDMAX (TDIE - TA)/θJA **(NOTE 2)**

* These parameters are characterized but not tested.

Note 1: IDD is current to run the chip alone without driving any load on the output pins.

2: T_A = Ambient temperature.

16.12 High Temperature Operation

This section outlines the specifications for the PIC12F615 device operating in a temperature range between -40°C and 150°C.(4) The specifications between -40°C and 150°C(4) are identical to those shown in DS41288 and DS80329.

Note 1: Writes are **not allowed** for Flash Program Memory above 125°C.

2: All AC timing specifications are increased by 30%. This derating factor will include parameters such as TPWRT.

3: The temperature range indicator in the part number is "H" for -40°C to 150°C.(4)

Example: PIC12F615T-H/ST indicates the device is shipped in a TAPE and reel configuration, in the MSOP package, and is rated for operation from -40°C to 150°C.(4)

4: AEC-Q100 reliability testing for devices intended to operate at 150°C is 1,000 hours. Any design in which the total operating time from 125°C to 150°C will be greater than 1,000 hours is not warranted without prior written approval from Microchip Technology Inc.

TABLE 16-13: ABSOLUTE MAXIMUM RATINGS

Parameter	Source/Sink	Value	Units
Max. Current: VDD	Source	20	mA
Max. Current: VSS	Sink	50	mA
Max. Current: PIN	Source	5	mA
Max. Current: PIN	Sink	10	mA
Pin Current: at VOH	Source	3	mA
Pin Current: at VOL	Sink	8.5	mA
Port Current: GPIO	Source	20	mA
Port Current: GPIO	Sink	50	mA
Maximum Junction Temperature		155	°C

Note: Stresses above those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure above maximum rating conditions for extended periods may affect device reliability.

TABLE 16-14: DC CHARACTERISTICS FOR IDD SPECIFICATIONS FOR PIC12F615-H (High Temp.)

Param No.	Device Characteristics	Units	Min	Typ	Max	Condition	
						VDD	Note
D010	Supply Current (IDD)	μA	—	13	58	2.0	IDD LP OSC (32 kHz)
			—	19	67	3.0	
			—	32	92	5.0	
D011		μA	—	135	316	2.0	IDD XT OSC (1 MHz)
			—	185	400	3.0	
			—	300	537	5.0	
D012		μA	—	240	495	2.0	IDD XT OSC (4 MHz)
			—	360	680	3.0	
		mA	—	0.660	1.20	5.0	
D013		μA	—	75	158	2.0	IDD EC OSC (1 MHz)
			—	155	338	3.0	
			—	345	792	5.0	
D014		μA	—	185	357	2.0	IDD EC OSC (4 MHz)
			—	325	625	3.0	
		mA	—	0.665	1.30	5.0	
D016		μA	—	245	476	2.0	IDD INTOSC (4 MHz)
			—	360	672	3.0	
			—	620	1.10	5.0	
D017		μA	—	395	757	2.0	IDD INTOSC (8 MHz)
		mA	—	0.620	1.20	3.0	
			—	1.20	2.20	5.0	
D018		μA	—	175	332	2.0	IDD EXTRC (4 MHz)
			—	285	518	3.0	
			—	530	972	5.0	
D019		mA	—	2.20	4.10	4.5	IDD HS OSC (20 MHz)
			—	2.80	4.80	5.0	

FIGURE 17-30: PIC12HV609/615 IPD CVREF (LOW RANGE) vs. VDD

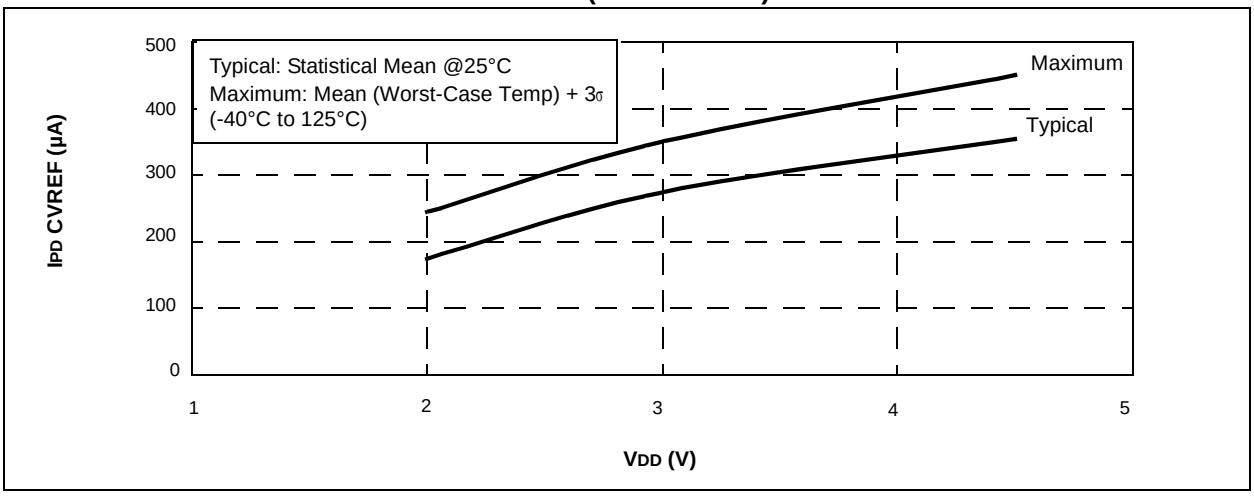


FIGURE 17-31: PIC12HV609/615 IPD CVREF (HI RANGE) vs. VDD

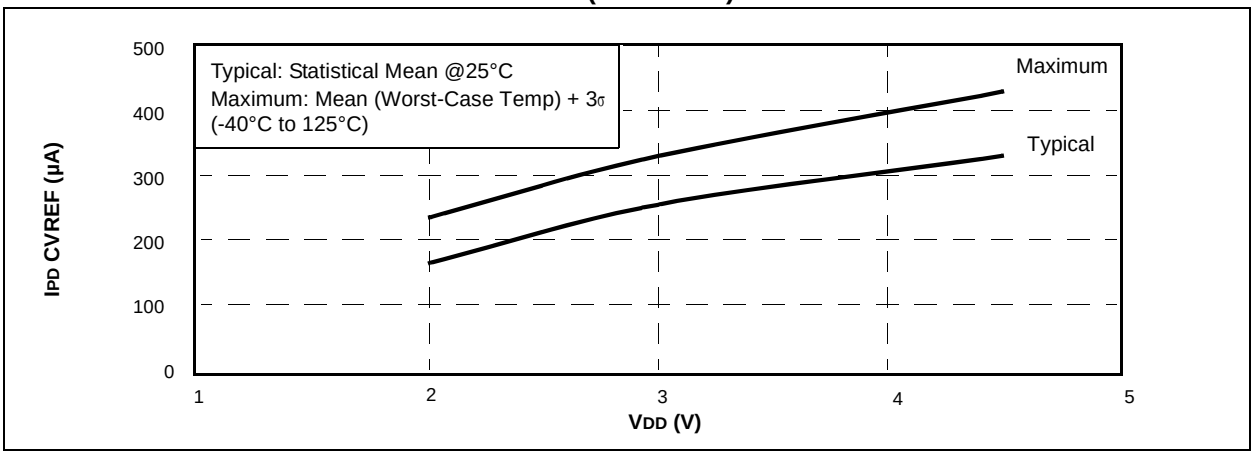
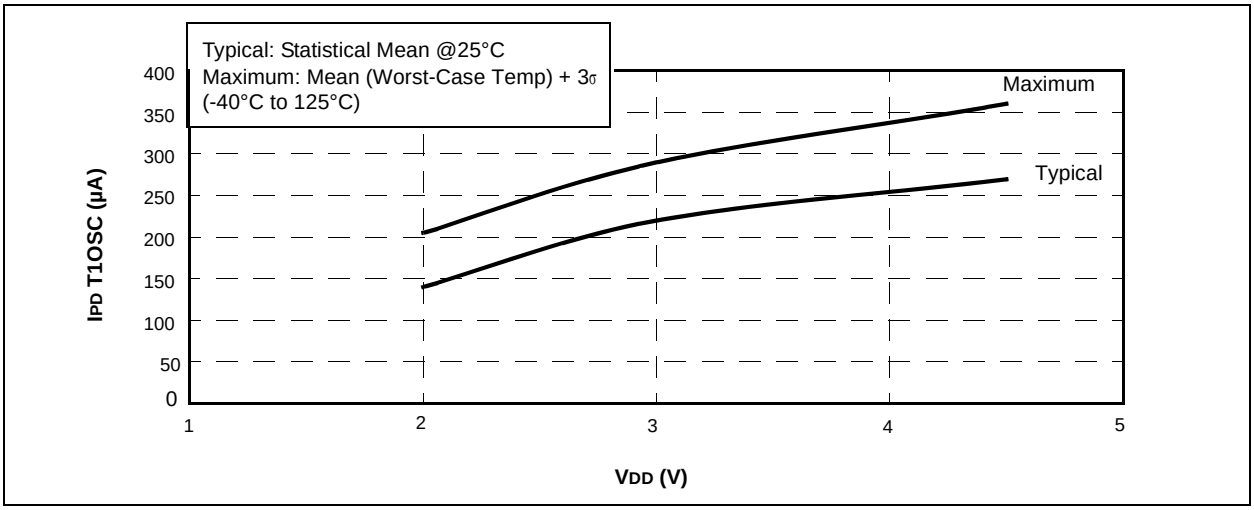
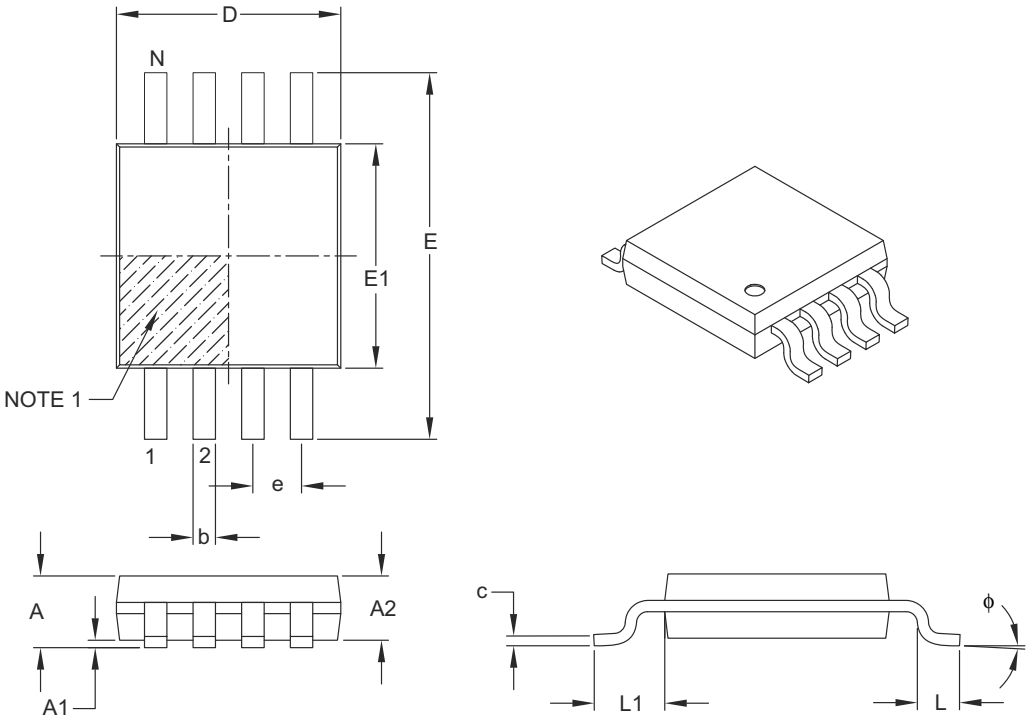


FIGURE 17-32: PIC12HV609/615 IPD T1OSC vs. VDD



8-Lead Plastic Micro Small Outline Package (MS) [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		8	
Pitch	e		0.65 BSC	
Overall Height	A	–	–	1.10
Molded Package Thickness	A2	0.75	0.85	0.95
Standoff	A1	0.00	–	0.15
Overall Width	E		4.90 BSC	
Molded Package Width	E1		3.00 BSC	
Overall Length	D		3.00 BSC	
Foot Length	L	0.40	0.60	0.80
Footprint	L1		0.95 REF	
Foot Angle	ϕ	0°	–	8°
Lead Thickness	c	0.08	–	0.23
Lead Width	b	0.22	–	0.40

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm per side.
3. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-111B